Supporting information

A Straightforward, Efficient, and Environment-Friendly Lithium Storage Tactic: Solventless fabrication of N/S Co-doped SiO_x/C with Carbon Encapsulation

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Figure S1. SEM image of N/S-Bulk-vinly-SiO₂-2.



Figure S2. XRD pattern of N/S-BM-vinly-SiO₂-2.



Figure S3. (a) N 1s spectra of NSBMSCC-1, NSBMSCC-2, and NSBMSCC-3. (b) S 2p spectra of NSBMSCC-1, NSBMSCC-2, and NSBMSCC-3.



Figure S4. (a) N 1s spectra of N/S-BM-vinly-SiO₂-2. (b) S 2p spectra of N/S-BM-vinly-SiO₂-2.



Figure S5. N₂ adsorption-desorption isotherms of BMSCC, NSBMSCC-1, NSBMSCC-2, and NSBMSCC-3.



Figure S6. CV curves of (a) BMSCC, (b) NSBMSCC-1, and (c) NSBMSCC-3.



Figure S7. (a) CV curves and (b) $\log i$ vs $\log v$ plots at different scan rates of BMSCC.



Figure S8. The capacitive contribution at 1.0 mV s⁻¹ of (a) NSBMSCC-2 and (b) BMSCC.



Figure S9. The equivalent circuit for data fitting.



Figure S10. Nyquist plots after different cycles of BMSCC.



Figure S11. GITT plot of BMSCC.



Figure S12. The electrodes SEM images of (a) BMSCC and (b) NSBMSCC-2 at 2 A

g⁻¹ after 600 cycles.

Element	Mass Fraction (%)			
С	30.55			
Ν	0.27			
Ο	39.71			
Si	29.24			
S	0.22			

 Table S1. The element mass fraction of NSBMSCC-2.

Sample	Ratio of precursor/(precursor+solve nt)	ICE	Current density (A g ⁻¹)	Cycle number	Capacity after cycling (mAh g ⁻¹)	Capacity retention (%)	Ref
NSBMSCC-2	1	74.2	2.0	600	595	96.1	This work
SiO _x /C@C NTS	0.011	64.6	0.5	450	511	75.7	29
CNT@SiO _x /C@C	0.009	54.2	2	1000	395	71.1	51
SiO _x /C-2	0.043	66.1	0.5	400	689	91	52
SiO _x @ZrO ₂ @C	0.14	50	0.5	500	413	72.2	53
SiO _x /G/C	0.021	84.3	0.12	350	524	81.3	54
SiO _x @C@Graphite	0.25	82.6	0.2	100	524	75.7	55
SiO _x -6/C	0.003	63.5	0.1	150	534	70.2	56
SiO _x /C	0.044	82.2	0.325	500	580	90	57
Hp-SiOC@VG	0.068	74.7	1	600	335	98	58
HSiO ₂ @CN	0.015	50	0.2	600	587	82	59
H-SiO ₂ /C	0.015	69.5	2	400	564	88.3	60

 Table S2. Comprehensive comparison of NSBMSCC-2 with past silicon-based anode

 materials.